

2.2 Low-power management

- Functional behavior predictable under all supply conditions
- Transceiver disengages from the bus when not powered up (zero load)

2.3 Protection

- High ElectroStatic Discharge (ESD) handling capability on the bus pins
- Bus pins protected against transients in automotive environments
- Transmit Data (TXD) dominant time-out function
- Undervoltage detection on pins V_{CC} and V_{IO}
- Thermally protected

3. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		4.5	-	5.5	V
V_{IO}	supply voltage on pin V_{IO}		2.8	-	5.5	V
$V_{uvd}(V_{CC})$	undervoltage detection voltage on pin V_{CC}		3.5	-	4.5	V
$V_{uvd}(V_{IO})$	undervoltage detection voltage on pin V_{IO}		1.3	2.0	2.7	V
I_{CC}	supply current	Silent mode	0.1	1	2.5	mA
		Normal mode; bus recessive	2.5	5	10	mA
		Normal mode; bus dominant	20	50	70	mA
I_{IO}	supply current on pin V_{IO}	Normal/Silent mode				
		recessive; $V_{TXD} = V_{IO}$	-	80	250	μ A
		dominant; $V_{TXD} = 0$ V	-	350	500	μ A
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2 at pins CANH and CANL	-8	-	+8	kV
V_{CANH}	voltage on pin CANH		-58	-	+58	V
V_{CANL}	voltage on pin CANL		-58	-	+58	V
T_{vj}	virtual junction temperature		-40	-	+150	$^{\circ}$ C

4. Ordering information

Table 2. Ordering information

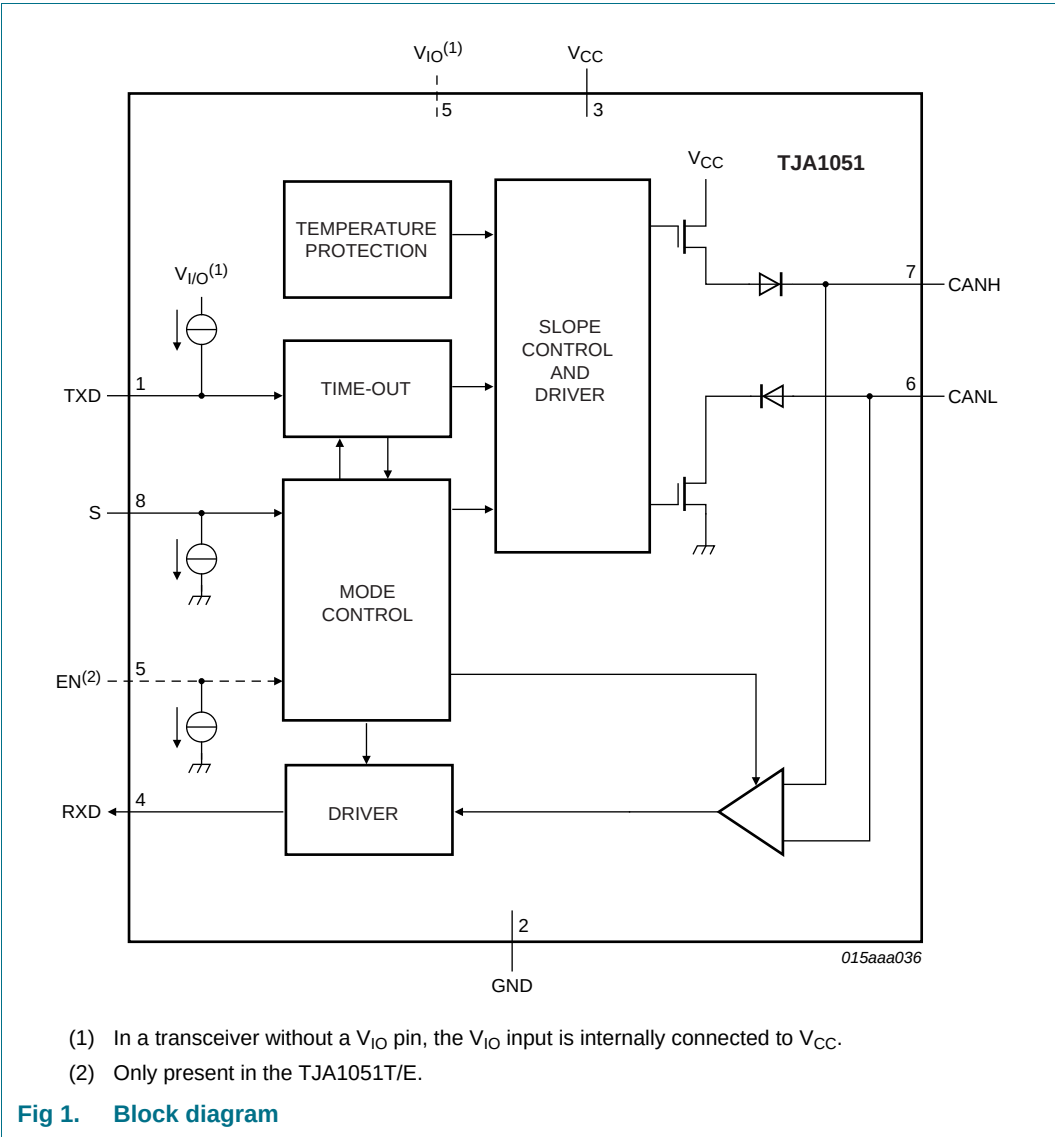
Type number	Package		
	Name	Description	Version
TJA1051T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

Table 2. Ordering information ...continued

Type number	Package		
	Name	Description	Version
TJA1051T/3 ^[1]	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1
TJA1051T/E ^[1]	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1
TJA1051TK/3 ^[1]	HVSON8	plastic thermal enhanced very thin small outline package; no leads; 8 terminals; body 3 × 3 × 0.85 mm	SOT782-1

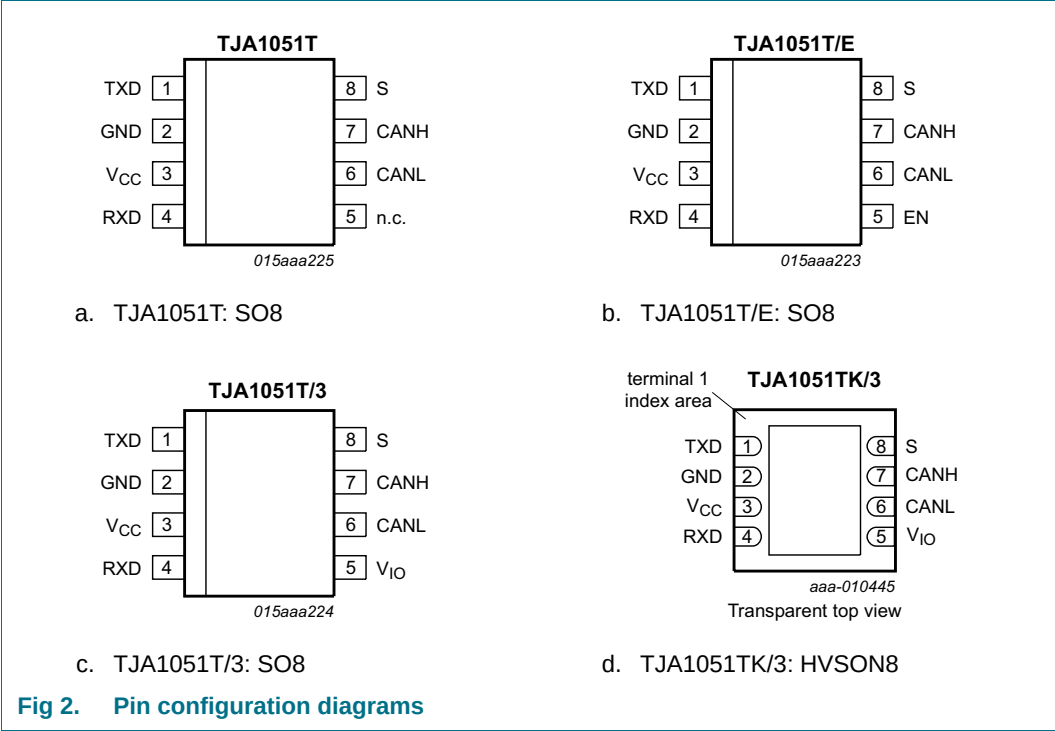
[1] TJA1051T/3 and TJA1051TK/3 with V_{IO} pin; TJA1051T/E with EN pin.

5. Block diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
TXD	1	transmit data input
GND ^[1]	2	ground
V _{CC}	3	supply voltage
RXD	4	receive data output; reads out data from the bus lines
n.c.	5	not connected; in TJA1051T version
EN	5	enable control input; TJA1051T/E only
V _{IO}	5	supply voltage for I/O level adapter; TJA1051T/3 and TJA1051TK/3 only
CANL	6	LOW-level CAN bus line
CANH	7	HIGH-level CAN bus line
S	8	Silent mode control input

[1] HVSON8 package die supply ground is connected to both the GND pin and the exposed center pad. The GND pin must be soldered to board ground. For enhanced thermal and electrical performance, it is recommended that the exposed center pad also be soldered to board ground.

7. Functional description

The TJA1051 is a high-speed CAN stand-alone transceiver with Silent mode. It combines the functionality of the TJA1050 transceiver with improved EMC and ESD handling capability. Improved slope control and high DC handling capability on the bus pins provides additional application flexibility.

The TJA1051 is available in three versions, distinguished only by the function of pin 5:

- The TJA1051T is backwards compatible with the TJA1050
- The TJA1051T/3 and TJA1051TK/3 allow for direct interfacing to microcontrollers with supply voltages down to 3 V
- The TJA1051T/E allows the transceiver to be switched to a very low-current Off mode.

7.1 Operating modes

The TJA1051 supports two operating modes, Normal and Silent, which are selected via pin S. An additional Off mode is supported in the TJA1051T/E via pin EN. See [Table 4](#) for a description of the operating modes under normal supply conditions.

Table 4. Operating modes

Mode	Inputs			Outputs	
	Pin EN ^[1]	Pin S	Pin TXD	CAN driver	Pin RXD
Normal	HIGH	LOW	LOW	dominant	active ^[2]
	HIGH	LOW	HIGH	recessive	active ^[2]
Silent	HIGH	HIGH	X ^[3]	recessive	active ^[2]
Off ^[1]	LOW	X ^[3]	X ^[3]	floating	floating

[1] Only available on the TJA1051T/E.

[2] LOW if the CAN bus is dominant, HIGH if the CAN bus is recessive.

[3] 'X' = don't care.

7.1.1 Normal mode

A LOW level on pin S selects Normal mode. In this mode, the transceiver is able to transmit and receive data via the bus lines CANH and CANL (see [Figure 1](#) for the block diagram). The differential receiver converts the analog data on the bus lines into digital data which is output to pin RXD. The slopes of the output signals on the bus lines are controlled internally and are optimized in a way that guarantees the lowest possible ElectroMagnetic Emission (EME).

7.1.2 Silent mode

A HIGH level on pin S selects Silent mode. In Silent mode the transmitter is disabled, releasing the bus pins to recessive state. All other IC functions, including the receiver, continue to operate as in Normal mode. Silent mode can be used to prevent a faulty CAN controller from disrupting all network communications.

7.1.3 Off mode

A LOW level on pin EN of TJA1051T/E selects Off mode. In Off mode the entire transceiver is disabled, allowing the microcontroller to save power when CAN communication is not required. The bus pins are floating in Off mode, making the transceiver invisible to the rest of the network.

7.2 Fail-safe features

7.2.1 TXD dominant time-out function

A 'TXD dominant time-out' timer is started when pin TXD is set LOW. If the LOW state on pin TXD persists for longer than $t_{\text{to}(\text{dom})\text{TXD}}$, the transmitter is disabled, releasing the bus lines to recessive state. This function prevents a hardware and/or software application failure from driving the bus lines to a permanent dominant state (blocking all network communications). The TXD dominant time-out timer is reset when pin TXD is set HIGH. The TXD dominant time-out time also defines the minimum possible bit rate of 20 kbit/s.

7.2.2 Internal biasing of TXD, S and EN input pins

Pin TXD has an internal pull-up to V_{IO} and pins S and EN (TJA1051T/E) have internal pull-downs to GND. This ensures a safe, defined state in case one or more of these pins is left floating.

7.2.3 Undervoltage detection on pins V_{CC} and V_{IO}

Should V_{CC} or V_{IO} drop below their respective undervoltage detection levels ($V_{\text{uvd}}(V_{\text{CC}})$ and $V_{\text{uvd}}(V_{\text{IO}})$; see [Table 7](#)), the transceiver will switch off and disengage from the bus (zero load) until V_{CC} and V_{IO} have recovered.

7.2.4 Overtemperature protection

The output drivers are protected against overtemperature conditions. If the virtual junction temperature exceeds the shutdown junction temperature, $T_{\text{j}(\text{sd})}$, the output drivers will be disabled until the virtual junction temperature falls below $T_{\text{j}(\text{sd})}$ and TXD becomes recessive again. Including the TXD condition ensures that output driver oscillations due to temperature drift are avoided.

7.3 V_{IO} supply pin

There are three versions of the TJA1051 available, only differing in the function of a single pin. Pin 5 is either an enable control input (EN), a V_{IO} supply pin or is not connected.

Pin V_{IO} on the TJA1051T/3 and TJA1051TK/3 should be connected to the microcontroller supply voltage (see [Figure 6](#)). This will adjust the signal levels of pins TXD, RXD and S to the I/O levels of the microcontroller. For versions of the TJA1051 without a V_{IO} pin, the V_{IO} input is internally connected to V_{CC} . This sets the signal levels of pins TXD, RXD and S to levels compatible with 5 V microcontrollers.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are referenced to GND.

Symbol	Parameter	Conditions	Min	Max	Unit
V _x	voltage on pin x ^[1]	on pins CANH, CANL	−58	+58	V
		on any other pin	−0.3	+7	V
V _(CANH-CANL)	voltage between pin CANH and pin CANL		−27	+27	V
V _{trt}	transient voltage	on pins CANH, CANL ^[2]			
		pulse 1	−100	-	V
		pulse 2a	-	75	V
		pulse 3a	−150	-	V
		pulse 3b	-	100	V
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (150 pF, 330 Ω) ^[3]			
		at pins CANH and CANL	−8	+8	kV
		Human Body Model (HBM); 100 pF, 1.5 kΩ ^[4]			
		at pins CANH and CANL	−8	+8	kV
		at any other pin	−4	+4	kV
		Machine Model (MM); 200 pF, 0.75 μH, 10 Ω ^[5]			
		at any pin	−300	+300	V
		Charged Device Model (CDM); field Induced charge; 4 pF ^[6]			
		at corner pins	−750	+750	V
		at any pin	−500	+500	V
T _{vj}	virtual junction temperature	^[7]	−40	+150	°C
T _{stg}	storage temperature		−55	+150	°C

- [1] The device can sustain voltages up to the specified values over the product lifetime, provided applied voltages (including transients) never exceed these values.
- [2] According to IEC TS 62228 (2007), Section 4.2.4; parameters for standard pulses defined in ISO7637 part 2: 2004-06.
- [3] According to IEC TS 62228 (2007), Section 4.3; DIN EN 61000-4-2.
- [4] According to AEC-Q100-002.
- [5] According to AEC-Q100-003.
- [6] AEC-Q100-011 Rev-C1. The classification level is C4B.
- [7] In accordance with IEC 60747-1. An alternative definition of virtual junction temperature is: $T_{vj} = T_{amb} + P \times R_{th(vj-a)}$, where $R_{th(vj-a)}$ is a fixed value to be used for the calculation of T_{vj} . The rating for T_{vj} limits the allowable combinations of power dissipation (P) and ambient temperature (T_{amb}).

9. Thermal characteristics

Table 6. Thermal characteristics

According to IEC 60747-1.

Symbol	Parameter	Conditions	Value	Unit
R _{th(vj-a)}	thermal resistance from virtual junction to ambient	SO8 package; in free air	155	K/W
		HVSON8 package; in free air	55	K/W

10. Static characteristics

Table 7. Static characteristics

$T_{vj} = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; $V_{CC} = 4.5\text{ V}$ to 5.5 V ; $V_{IO} = 2.8\text{ V}$ to 5.5 V ^[1]; $R_L = 60\text{ }\Omega$ unless specified otherwise; All voltages are defined with respect to ground; Positive currents flow into the IC^[2].

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Supply; pin V_{CC}						
V _{CC}	supply voltage		4.5	-	5.5	V
I _{CC}	supply current	Off mode (TJA1051T/E)	1	5	8	μA
		Silent mode	0.1	1	2.5	mA
		Normal mode				
		recessive; $V_{TXD} = V_{IO}$ ^[3]	-	5	10	mA
		dominant; $V_{TXD} = 0\text{ V}$	-	50	70	mA
V _{uvd(VCC)}	undervoltage detection voltage on pin V _{CC}	dominant; $V_{TXD} = 0\text{ V}$; short circuit on bus lines; $-3\text{ V} < (V_{CANH} = V_{CANL}) < +18\text{ V}$	2.5	80	110	mA
I/O level adapter supply; pin V_{IO} ^[1]						
V _{IO}	supply voltage on pin V _{IO}		2.8	-	5.5	V
I _{IO}	supply current on pin V _{IO}	Normal/Silent mode				
		recessive; $V_{TXD} = V_{IO}$ ^[3]	-	80	250	μA
		dominant; $V_{TXD} = 0\text{ V}$	-	350	500	μA
V _{uvd(VIO)}	undervoltage detection voltage on pin V _{IO}		1.3	2.0	2.7	V
Mode control inputs; pins S and EN ^[4]						
V _{IH}	HIGH-level input voltage	^[5]	$0.7V_{IO}$ ^[3]	-	$V_{IO} + 0.3$ ^[3]	V
V _{IL}	LOW-level input voltage		-0.3	-	$0.3V_{IO}$ ^[3]	V
I _{IH}	HIGH-level input current	$V_S = V_{IO}$; $V_{EN} = V_{IO}$ ^[3]	1	4	10	μA
I _{IL}	LOW-level input current	$V_S = 0\text{ V}$; $V_{EN} = 0\text{ V}$	-1	0	+1	μA
CAN transmit data input; pin TXD						
V _{IH}	HIGH-level input voltage	^[5]	$0.7V_{IO}$ ^[3]	-	$V_{IO} + 0.3$ ^[3]	V
V _{IL}	LOW-level input voltage		-0.3	-	$+0.3V_{IO}$ ^[3]	V
I _{IH}	HIGH-level input current	$V_{TXD} = V_{IO}$ ^[3]	-5	0	+5	μA
I _{IL}	LOW-level input current	Normal mode; $V_{TXD} = 0\text{ V}$	-260	-150	-30	μA
C _i	input capacitance	^[6]	-	5	10	pF
CAN receive data output; pin RXD						
I _{OH}	HIGH-level output current	$V_{RXD} = V_{IO} - 0.4\text{ V}$ ^[3]	-8	-3	-1	mA
I _{OL}	LOW-level output current	$V_{RXD} = 0.4\text{ V}$; bus dominant	2	5	12	mA
Bus lines; pins CANH and CANL						
V _{O(dom)}	dominant output voltage	$V_{TXD} = 0\text{ V}$; $t < t_{to(dom)TXD}$				
		pin CANH; $R_L = 50\text{ }\Omega$ to $65\text{ }\Omega$	2.75	3.5	4.5	V
		pin CANL; $R_L = 50\text{ }\Omega$ to $65\text{ }\Omega$	0.5	1.5	2.25	V
V _{dom(TX)sym}	transmitter dominant voltage symmetry	$V_{dom(TX)sym} = V_{CC} - V_{CANH} - V_{CANL}$	-400	-	+400	mV

Table 7. Static characteristics ...continued

$T_{vj} = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; $V_{CC} = 4.5\text{ V}$ to 5.5 V ; $V_{IO} = 2.8\text{ V}$ to 5.5 V ^[1]; $R_L = 60\text{ }\Omega$ unless specified otherwise; All voltages are defined with respect to ground; Positive currents flow into the IC^[2].

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{TXsym}	transmitter voltage symmetry	$V_{TXsym} = V_{CANH} + V_{CANL}$; ^[6] $f_{TXD} = 250\text{ kHz}$, 1 MHz and 2.5 MHz ; ^[7] $V_{CC} = 4.75\text{ V}$ to 5.25 V ; $C_{SPLIT} = 4.7\text{ nF}$	$0.9V_{CC}$	-	$1.1V_{CC}$	V
$V_{O(dif)}$	differential output voltage	dominant: Normal mode; $V_{TXD} = 0\text{ V}$; $t < t_{to(dom)TXD}$; $V_{CC} = 4.75\text{ V}$ to 5.25 V				
		$R_L = 45\text{ }\Omega$ to $65\text{ }\Omega$	1.5	-	3	V
		$R_L = 45\text{ }\Omega$ to $70\text{ }\Omega$	1.5	-	3.3	V
		$R_L = 2240\text{ }\Omega$	1.5	-	5	V
		recessive; no load				
		Normal mode: $V_{TXD} = V_{IO}$ ^[3]	-50	-	+50	mV
$V_{O(rec)}$	recessive output voltage	Normal/Silent mode; $V_{TXD} = V_{IO}$ ^[3] ; no load	2	$0.5V_{CC}$	3	V
$V_{th(RX)dif}$	differential receiver threshold voltage	Normal/Silent mode; $-30\text{ V} \leq V_{CANL} \leq +30\text{ V}$; $-30\text{ V} \leq V_{CANH} \leq +30\text{ V}$	0.5	0.7	0.9	V
$V_{rec(RX)}$	receiver recessive voltage	Normal/Silent mode; $-30\text{ V} \leq V_{CANL} \leq +30\text{ V}$; $-30\text{ V} \leq V_{CANH} \leq +30\text{ V}$	-4	-	0.5	V
$V_{dom(RX)}$	receiver dominant voltage	Normal/Silent mode; $-30\text{ V} \leq V_{CANL} \leq +30\text{ V}$; $-30\text{ V} \leq V_{CANH} \leq +30\text{ V}$	0.9	-	9.0	V
$V_{hys(RX)dif}$	differential receiver hysteresis voltage	Normal/Silent mode; $-30\text{ V} \leq V_{CANL} \leq +30\text{ V}$; $-30\text{ V} \leq V_{CANH} \leq +30\text{ V}$	50	120	200	mV
$I_{O(sc)dom}$	dominant short-circuit output current	$V_{TXD} = 0\text{ V}$; $t < t_{to(dom)TXD}$; $V_{CC} = 5\text{ V}$				
		pin CANH; $V_{CANH} = -15\text{ V}$ to $+40\text{ V}$	-100	-70	-40	mA
		pin CANL; $V_{CANL} = -15\text{ V}$ to $+40\text{ V}$	40	70	100	mA
$I_{O(sc)rec}$	recessive short-circuit output current	Normal/Silent mode; $V_{TXD} = V_{IO}$ ^[3] ; $V_{CANH} = V_{CANL} = -27\text{ V}$ to $+32\text{ V}$	-5	-	+5	mA
I_L	leakage current	$V_{CC} = V_{IO} = 0\text{ V}$ or $V_{CC} = V_{IO} =$ shorted to ground via $47\text{ k}\Omega$; $V_{CANH} = V_{CANL} = 5\text{ V}$	-5	0	+5	μA
R_i	input resistance	$-2\text{ V} \leq V_{CANL} \leq +7\text{ V}$; ^[6] $-2\text{ V} \leq V_{CANH} \leq +7\text{ V}$	9	15	28	$\text{k}\Omega$
ΔR_i	input resistance deviation	$0\text{ V} \leq V_{CANL} \leq +5\text{ V}$; ^[6] $0\text{ V} \leq V_{CANH} \leq +5\text{ V}$	-1	-	+1	%
$R_{i(dif)}$	differential input resistance	$-2\text{ V} \leq V_{CANL} \leq +7\text{ V}$; ^[6] $-2\text{ V} \leq V_{CANH} \leq +7\text{ V}$	19	30	52	$\text{k}\Omega$
$C_{i(cm)}$	common-mode input capacitance	^[6]	-	-	20	pF

Table 7. Static characteristics ...continued

$T_{vj} = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; $V_{CC} = 4.5\text{ V}$ to 5.5 V ; $V_{IO} = 2.8\text{ V}$ to 5.5 V ^[1]; $R_L = 60\text{ }\Omega$ unless specified otherwise; All voltages are defined with respect to ground; Positive currents flow into the IC^[2].

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$C_{i(dif)}$	differential input capacitance	[6]	-	-	10	pF
Temperature protection						
$T_{j(sd)}$	shutdown junction temperature	[6]	-	190	-	$^{\circ}\text{C}$

- [1] Only TJA1051T/3 and TJA1051TK/3 have a V_{IO} pin. In transceivers without a V_{IO} pin, the V_{IO} input is internally connected to V_{CC} .
- [2] All parameters are guaranteed over the virtual junction temperature range by design. Factory testing uses correlated test conditions to cover the specified temperature and power supply voltage range.
- [3] $V_{IO} = V_{CC}$ for the non- V_{IO} product variants TJA1051T(E)
- [4] Only TJA1051T/E has an EN pin.
- [5] Maximum value assumes $V_{CC} < V_{IO}$; if $V_{CC} > V_{IO}$, the maximum value will be $V_{CC} + 0.3\text{ V}$.
- [6] Not tested in production; guaranteed by design.
- [7] The test circuit used to measure the bus output voltage symmetry (which includes C_{SPLIT}) is shown in Figure 8.

11. Dynamic characteristics

Table 8. Dynamic characteristics

$T_{vj} = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; $V_{CC} = 4.5\text{ V}$ to 5.5 V ; $V_{IO} = 2.8\text{ V}$ to 5.5 V ^[1]; $R_L = 60\text{ }\Omega$ unless specified otherwise. All voltages are defined with respect to ground. Positive currents flow into the IC^[2].

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Transceiver timing; pins CANH, CANL, TXD and RXD; see Figure 7 and Figure 3						
$t_d(\text{TXD-busdom})$	delay time from TXD to bus dominant	Normal mode	-	65	-	ns
$t_d(\text{TXD-busrec})$	delay time from TXD to bus recessive	Normal mode	-	90	-	ns
$t_d(\text{busdom-RXD})$	delay time from bus dominant to RXD	Normal/Silent mode	-	60	-	ns
$t_d(\text{busrec-RXD})$	delay time from bus recessive to RXD	Normal/Silent mode	-	65	-	ns
$t_d(\text{TXDL-RXDL})$	delay time from TXD LOW to RXD LOW	Normal mode: versions with V_{IO} pin	40	-	250	ns
		Normal mode: other versions	40	-	220	ns
$t_d(\text{TXDH-RXDH})$	delay time from TXD HIGH to RXD HIGH	Normal mode: versions with V_{IO} pin	40	-	250	ns
		Normal mode: other versions	40	-	220	ns
$t_{bit}(\text{bus})$	transmitted recessive bit width	$t_{bit}(\text{TXD}) = 500\text{ ns}$ [3]	435	-	530	ns
		$t_{bit}(\text{TXD}) = 200\text{ ns}$ [3]	155	-	210	ns
$t_{bit}(\text{RXD})$	bit time on pin RXD	$t_{bit}(\text{TXD}) = 500\text{ ns}$ [3]	400	-	550	ns
		$t_{bit}(\text{TXD}) = 200\text{ ns}$ [3]	120	-	220	ns
Δt_{rec}	receiver timing symmetry	$t_{bit}(\text{TXD}) = 500\text{ ns}$	-65	-	+40	ns
		$t_{bit}(\text{TXD}) = 200\text{ ns}$	-45	-	+15	ns
$t_{to(dom)TXD}$	TXD dominant time-out time	$V_{TXD} = 0\text{ V}$; Normal mode [4]	0.3	1	5	ms

- [1] Only TJA1051T/3 and TJA1051TK/3 have a V_{IO} pin. In transceivers without a V_{IO} pin, the V_{IO} input is internally connected to V_{CC} .
- [2] All parameters are guaranteed over the virtual junction temperature range by design. Factory testing uses correlated test conditions to cover the specified temperature and power supply voltage range.

- [3] See [Figure 4](#).
- [4] Minimum value of 0.8ms required according to SAE J2284; 0.3ms is allowed according to ISO11898-2:2016 for legacy devices.

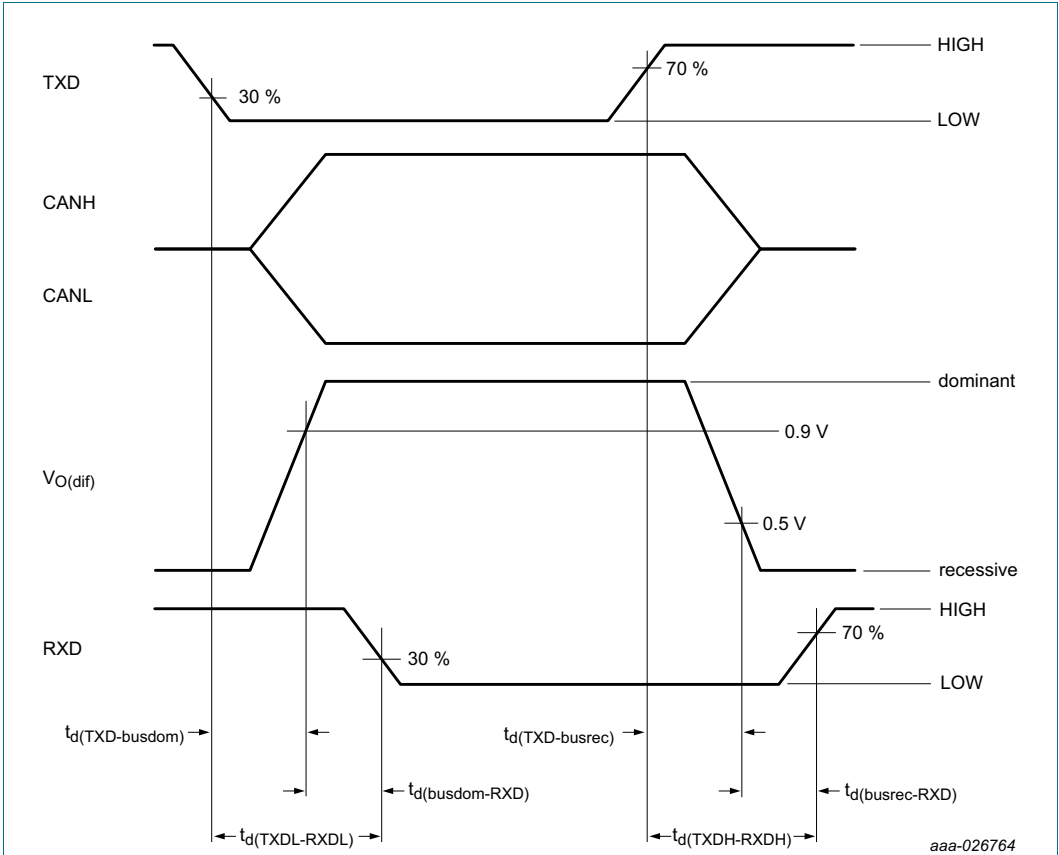
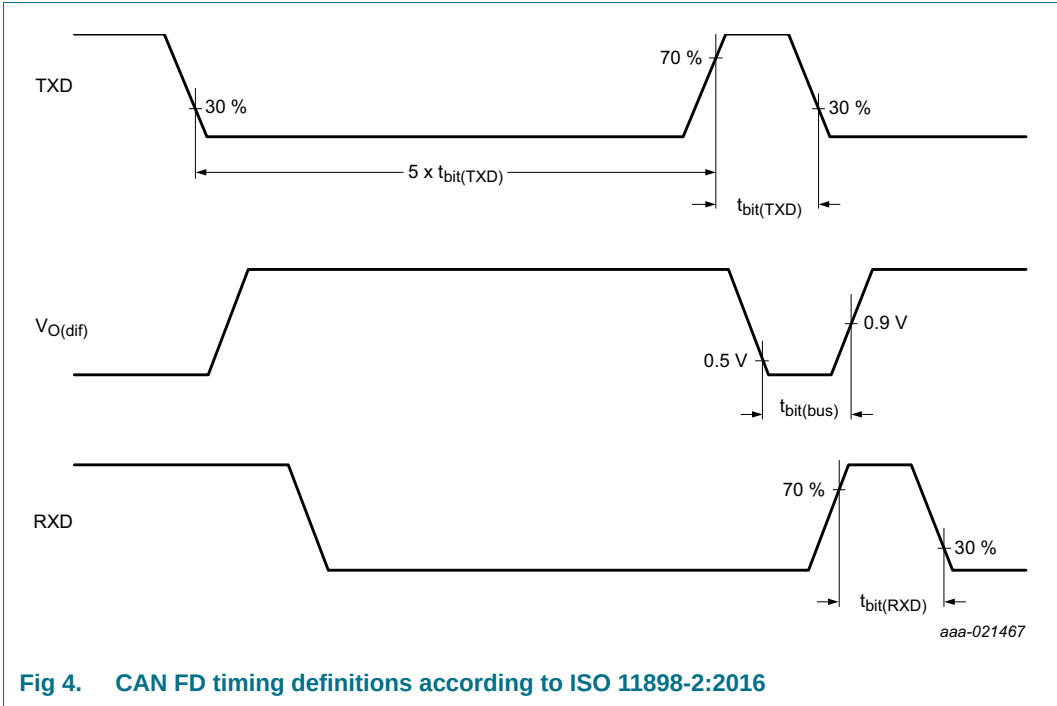
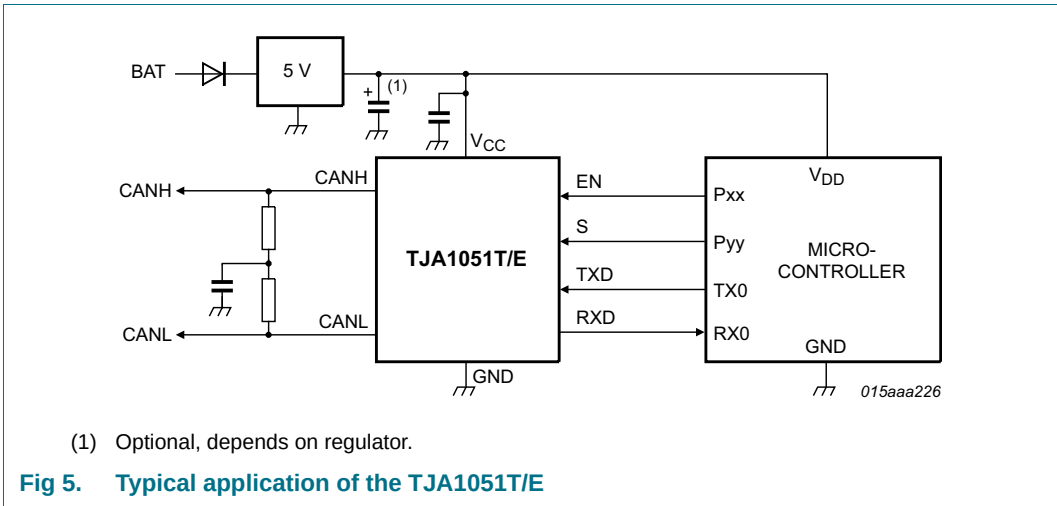


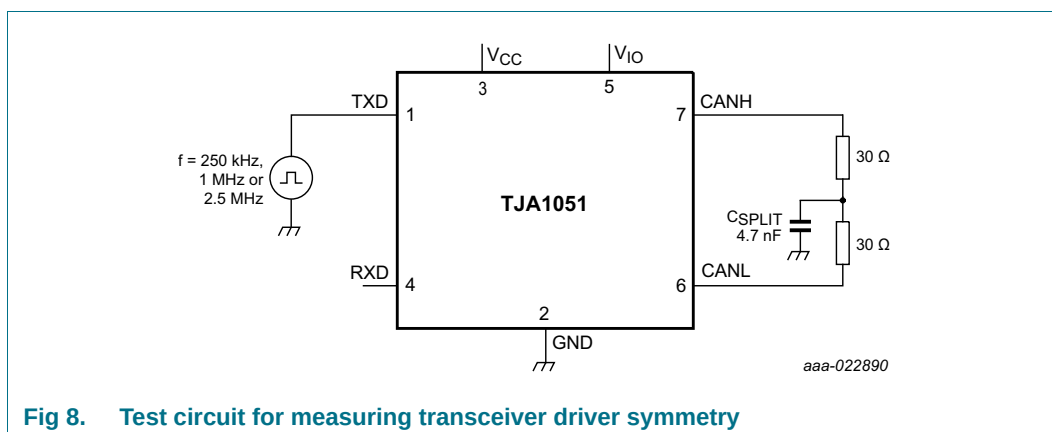
Fig 3. CAN transceiver timing diagram



12. Application information

12.1 Application diagrams





13.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q100 Rev-G - *Failure mechanism based stress test qualification for integrated circuits*, and is suitable for use in automotive applications.

14. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

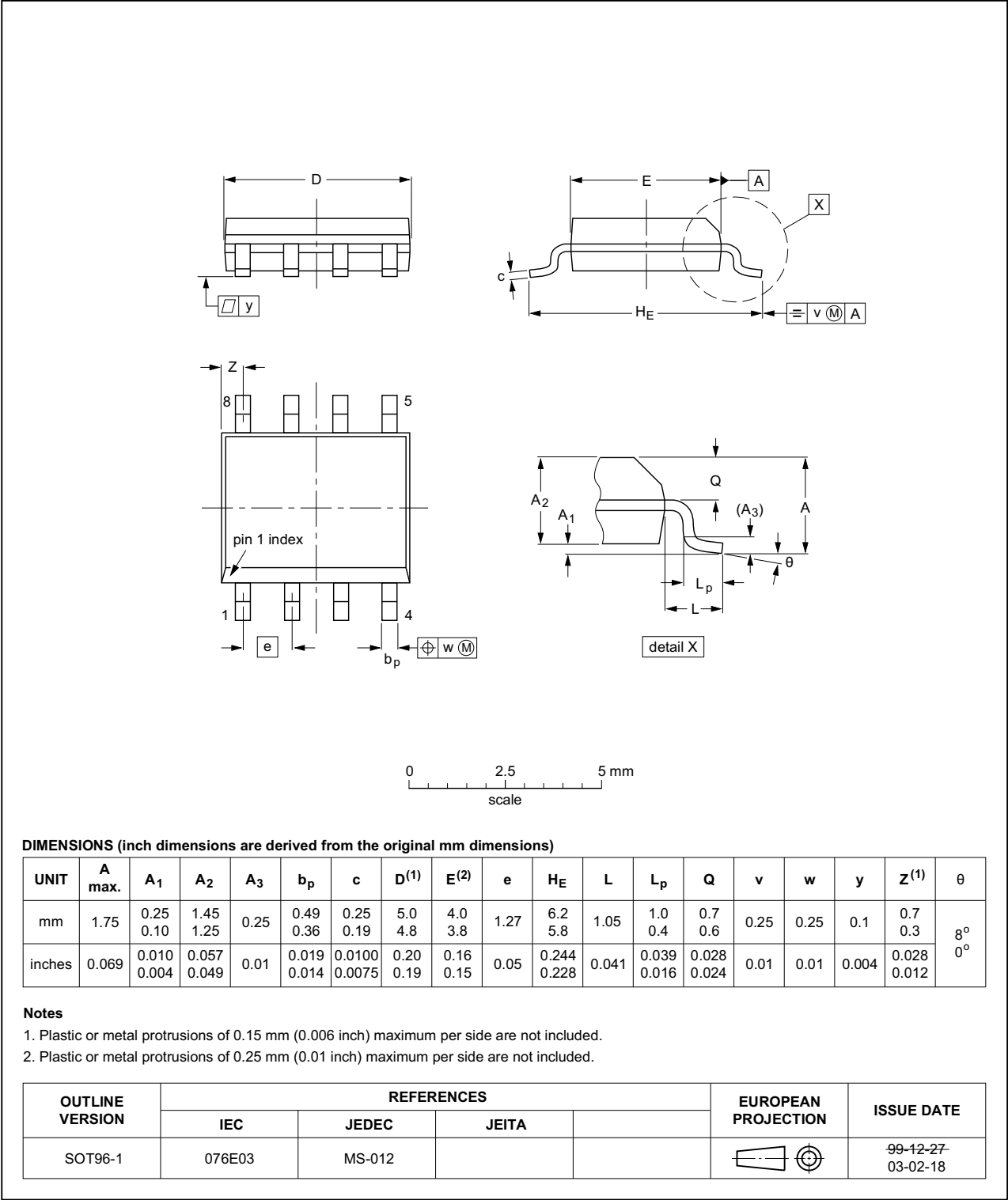


Fig 9. Package outline SOT96-1 (SO8)

HVSON8: plastic thermal enhanced very thin small outline package; no leads;
8 terminals; body 3 x 3 x 0.85 mm

SOT782-1

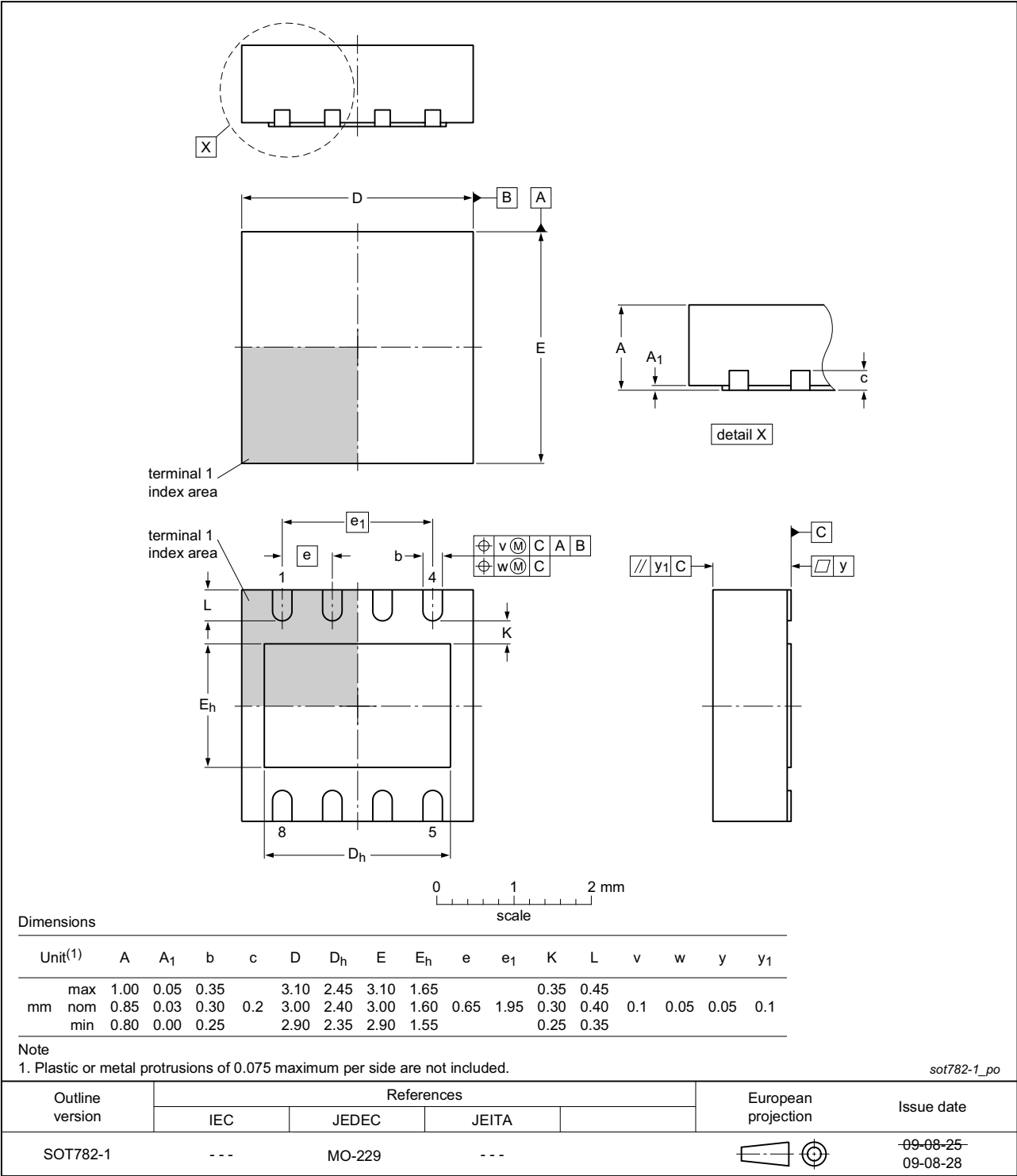


Fig 10. Package outline SOT782-1 (HVSON8)

15. Handling information

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling ensure that the appropriate precautions are taken as described in *JESD625-A* or equivalent standards.

16. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

16.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

16.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

16.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

16.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see [Figure 11](#)) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with [Table 9](#) and [10](#)

Table 9. SnPb eutectic process (from J-STD-020D)

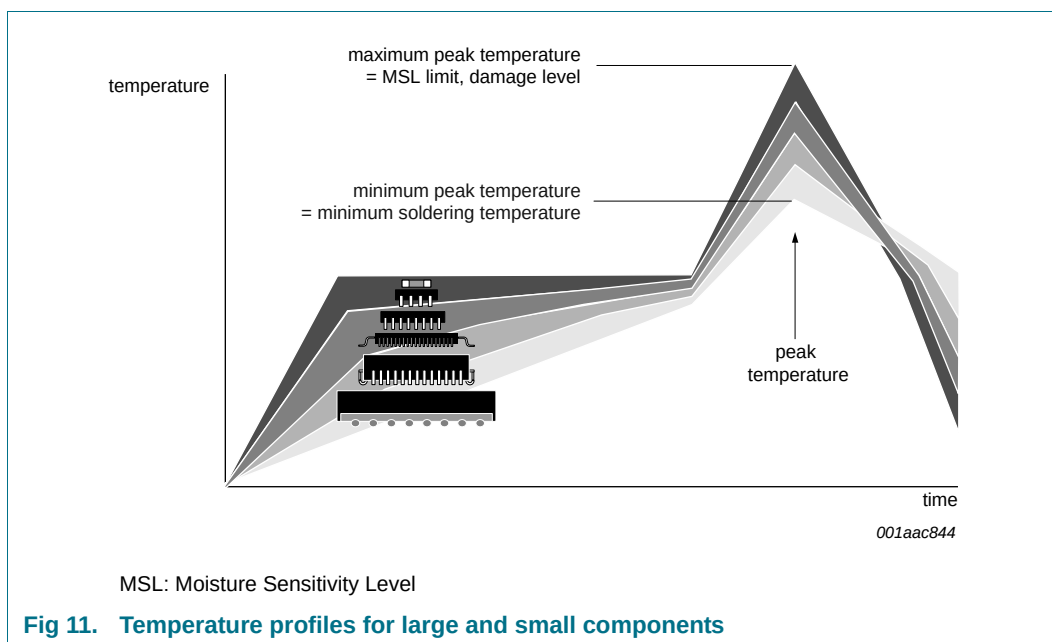
Package thickness (mm)	Package reflow temperature (°C)	
	Volume (mm ³)	
	< 350	≥ 350
< 2.5	235	220
≥ 2.5	220	220

Table 10. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm ³)		
	< 350	350 to 2000	> 2000
< 1.6	260	260	260
1.6 to 2.5	260	250	245
> 2.5	250	245	245

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see [Figure 11](#).



For further information on temperature profiles, refer to Application Note AN10365 "Surface mount reflow soldering description".

17. Soldering of HVSON packages

[Section 17](#) contains a brief introduction to the techniques most commonly used to solder Surface Mounted Devices (SMD). A more detailed discussion on soldering HVSON leadless package ICs can be found in the following application notes:

- AN10365 "Surface mount reflow soldering description"
- AN10366 "HVQFN application information"

18. Appendix: ISO 11898-2:2016 parameter cross-reference list

Table 11. ISO 11898-2:2016 to NXP data sheet parameter conversion

ISO 11898-2:2016		NXP data sheet	
Parameter	Notation	Symbol	Parameter
HS-PMA dominant output characteristics			
Single ended voltage on CAN_H	V _{CAN_H}	V _{O(dom)}	dominant output voltage
Single ended voltage on CAN_L	V _{CAN_L}		
Differential voltage on normal bus load	V _{Diff}	V _{O(dif)}	differential output voltage
Differential voltage on effective resistance during arbitration			
Optional: Differential voltage on extended bus load range			
HS-PMA driver symmetry			
Driver symmetry	V _{SYM}	V _{TXsym}	transmitter voltage symmetry
Maximum HS-PMA driver output current			
Absolute current on CAN_H	I _{CAN_H}	I _{O(sc)dom}	dominant short-circuit output current
Absolute current on CAN_L	I _{CAN_L}		
HS-PMA recessive output characteristics, bus biasing active/inactive			
Single ended output voltage on CAN_H	V _{CAN_H}	V _{O(rec)}	recessive output voltage
Single ended output voltage on CAN_L	V _{CAN_L}		
Differential output voltage	V _{Diff}	V _{O(dif)}	differential output voltage
Optional HS-PMA transmit dominant timeout			
Transmit dominant timeout, long	t _{dom}	t _{to(dom)TXD}	TXD dominant time-out time
Transmit dominant timeout, short			
HS-PMA static receiver input characteristics, bus biasing active/inactive			
Recessive state differential input voltage range	V _{Diff}	V _{th(RX)dif}	differential receiver threshold voltage
Dominant state differential input voltage range		V _{rec(RX)}	receiver recessive voltage
		V _{dom(RX)}	receiver dominant voltage
HS-PMA receiver input resistance (matching)			
Differential internal resistance	R _{Diff}	R _{i(dif)}	differential input resistance
Single ended internal resistance	R _{CAN_H} R _{CAN_L}	R _i	input resistance
Matching of internal resistance	MR	ΔR _i	input resistance deviation
HS-PMA implementation loop delay requirement			
Loop delay	t _{Loop}	t _{d(TXDH-RXDH)}	delay time from TXD HIGH to RXD HIGH
		t _{d(TXDL-RXDL)}	delay time from TXD LOW to RXD LOW
Optional HS-PMA implementation data signal timing requirements for use with bit rates above 1 Mbit/s up to 2 Mbit/s and above 2 Mbit/s up to 5 Mbit/s			
Transmitted recessive bit width @ 2 Mbit/s / @ 5 Mbit/s, intended	t _{Bit(Bus)}	t _{bit(bus)}	transmitted recessive bit width
Received recessive bit width @ 2 Mbit/s / @ 5 Mbit/s	t _{Bit(RXD)}	t _{bit(RXD)}	bit time on pin RXD
Receiver timing symmetry @ 2 Mbit/s / @ 5 Mbit/s	Δt _{Rec}	Δt _{rec}	receiver timing symmetry

Table 11. ISO 11898-2:2016 to NXP data sheet parameter conversion ...continued

ISO 11898-2:2016		NXP data sheet	
Parameter	Notation	Symbol	Parameter
HS-PMA maximum ratings of V _{CAN_H} , V _{CAN_L} and V _{Diff}			
Maximum rating V _{Diff}	V _{Diff}	V _(CANH-CANL)	voltage between pin CANH and pin CANL
General maximum rating V _{CAN_H} and V _{CAN_L}	V _{CAN_H}	V _x	voltage on pin x
Optional: Extended maximum rating VCAN_H and VCAN_L	V _{CAN_L}		
HS-PMA maximum leakage currents on CAN_H and CAN_L, unpowered			
Leakage current on CAN_H, CAN_L	I _{CAN_H} I _{CAN_L}	I _L	leakage current
HS-PMA bus biasing control timings			
CAN activity filter time, long	t _{Filter}	t _{wake(busdom)} ^[1]	bus dominant wake-up time
CAN activity filter time, short		t _{wake(busrec)} ^[1]	bus recessive wake-up time
Wake-up timeout, short	t _{Wake}	t _{to(wake)bus}	bus wake-up time-out time
Wake-up timeout, long			
Timeout for bus inactivity	t _{Silence}	t _{to(silence)}	bus silence time-out time
Bus Bias reaction time	t _{Bias}	t _{d(busact-bias)}	delay time from bus active to bias

[1] $t_{fltr(wake)bus}$ - bus wake-up filter time, in devices with basic wake-up functionality

19. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TJA1051 v.9	20171128	Product data sheet	-	TJA1051 v.8.1
Modifications:	- Updated to comply with ISO 11898-2:2016 and SAE J2284-1 through SAE J2284-5 specifications: Section 1: text amended (2nd last paragraph) Section 2.1: text amended (1st entry) Table 7: values changed and/or measurements conditions amended/added for parameters I_{CC}, $V_{dom(TX)sym}$, V_{TXsym}, $V_{O(dif)}$, $V_{rec(RX)}$, $V_{dom(RX)}$, $I_{O(sc)dom}$, R_i, ΔR_i and $R_{i(dif)}$ Table 8: Table note 4 added Figure 3: thresholds clarified Figure 4: title changed Figure 5, Figure 6, Figure 8: amended			
TJA1051 v.8.1	20160712	Product data sheet	-	TJA1051 v.7
TJA1051 v.7	20150115	Product data sheet	-	TJA1051 v.6
TJA1051 v.6	20110325	Product data sheet	-	TJA1051 v.5
TJA1051 v.5	20101229	Product data sheet	-	TJA1051 v.4
TJA1051 v.4	20091020	Product data sheet	-	TJA1051 v.3
TJA1051 v.3	20090825	Product data sheet	-	TJA1051 v.2
TJA1051 v.2	20090701	Product data sheet	-	TJA1051 v.1
TJA1051 v.1	20090309	Product data sheet	-	-

20. Legal information

20.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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